

Wet chemical synthesis and characterization of SnS₂ nanoparticles

Sunil H. Chaki · M. P. Deshpande ·
Devangini P. Trivedi · Jiten P. Tailor ·
Mahesh D. Chaudhary · Kanchan Mahato

Received: 29 October 2011 / Accepted: 9 April 2012 / Published online: 27 April 2012
© The Author(s) 2012. This article is published with open access at Springerlink.com

Abstract The SnS₂ nanoparticles were synthesized at room temperature by simple wet chemical method. Stannic chloride pentahydrate (SnCl₄·5H₂O) and thioacetamide (C₂H₅NS) were used as a source of Sn⁺⁴ ions and S⁻² ions, respectively. The elemental composition of the as-synthesized SnS₂ nanoparticles was determined by energy dispersive analysis of X-ray. The structure and lattice parameters were determined by X-ray diffraction. The crystallite size was determined from XRD pattern using Scherrer's formula and Hall–Williamson plot. The transmission electron microscopy was employed to characterize the nanoparticles. The selected area electron diffraction pattern established the polycrystalline nature of SnS₂ nanoparticles. Surface topography of nanoparticles was studied employing scanning electron microscopy (SEM). The bandgap determined from the UV–Vis–NIR spectrum of as-synthesized SnS₂ nanoparticles showed blue shift in comparison with the bandgap of bulk SnS₂. The photoluminescence spectra at five different excitation wavelengths 250, 300, 350, 400 and 450 nm showed two strong emission peaks at wavelengths 550 and 825 nm. The obtained results are discussed in details.

Keywords SnS₂ nanoparticles · Wet chemical method · Transmission electron microscopy · Scanning electron microscopy · Optical absorbance · Photoluminescence

Introduction

In the recent years, zero-dimensional nanostructural metal sulphide semiconductors have attracted much attention due to their physical and chemical properties. The metal sulphide semiconductors of zero-dimension are currently recognized as advanced inorganic materials with nonconventional applications due to the quantum size effect. These nanostructures in particular show remarkable electronic (Yi and Schwarzacher 1999), magnetic (Ross et al. 2002), optical (Zhang et al. 2011), etc. properties, which have great potential applications in the next generation of nanodevices (Zach et al. 2000). Among the semiconductors, tin disulfide (SnS₂) is an important CdI₂-type IV–VI group layered semiconductor with an optical band gap of about 2.2–2.35 eV (Zhang et al. 2010; Yang et al. 2009) which is little smaller than that of CdS. Such a tuneable band gap of SnS₂ makes it a potential candidate for efficient solar cell (Loferski 1956). It is also of interest in holographic recording system and electrical switching (Chun et al. 1994; Patil and Fredgold 1971). SnS₂ is non-poisonous, relatively inexpensive and chemically stable in acid or neutral aqueous solution, thus it has the potential to be a good visible light-sensitive photocatalyst (Zhang et al. 2010; Yang et al. 2009; He et al. 2007). It is also an interesting material that belongs to the class of isomorphous materials that exhibit a strong anisotropy of optical properties (Agrawal et al. 1994).

Many synthesis methods have been employed to prepare SnS₂ nanoparticles including soft chemical reaction, solid-state reaction, sol–gel process, hydrothermal (Li et al. 2009; Rao et al. 2004) microwave heating (Lokhande 1990) photo etching (Gaponendo 1998), and reverse micelles, etc. The wet chemical method is relatively inexpensive, non-toxic, less time consuming and very simple because it contains

S. H. Chaki (✉) · M. P. Deshpande · D. P. Trivedi ·
J. P. Tailor · M. D. Chaudhary · K. Mahato
Department of Physics, Sardar Patel University,
Vallabh Vidyanagar, 388 120 Gujarat, India
e-mail: sunilchaki@yahoo.co.in

few chemicals and does not require any sophisticated expensive instruments. In this paper, the authors report the synthesis of SnS₂ nanoparticles by a wet chemical method at room temperature (R.T.) using stannic chloride pentahydrate (SnCl₄·5H₂O) and thioacetamide (C₂H₅NS) as a precursor. The study of the stoichiometric composition, structural, surface morphology, optical and luminescence properties of the as-synthesized nanoparticles was carried out.

Experimental

Synthesis of SnS₂ nanoparticles

All chemicals for the synthesis of SnS₂ nanoparticles such as stannic chloride pentahydrate (SnCl₄·5H₂O), thioacetamide (C₂H₅NS), and concentrated hydrochloric acid (HCl 35 % pure A.R.) were of analytical grade and used as received without further purification. In the typical synthesis, 0.806 g (2.3 mmol) of SnCl₄·5H₂O was dissolved in 2 ml of concentrated HCl acid (35 %, w/w) in a 100 ml beaker. Then, 30 ml distilled water was added and stirring was done for 5 min. It acts as a source of Sn⁺⁴ ions. After 5 min stirring, 0.25 g (3.3 mmol) of thioacetamide was added to the solution under constant stirring. Thioacetamide was the source of S⁻² ions. The stirring was continued for 3 h. During this period, solution turned into yellow color and lastly 18 ml distilled water was added to make the final solution of 50 ml. The final solution was kept isolated for 25–30 min to allow particles to settle down at the bottom of the beaker. The yellow precipitates settled at the bottom of the beaker were filtered and washed with distilled water followed with methanol for several times to obtain SnS₂ nanoparticles. After multiple washes, they were dried in oven at 40 °C for 6 h. Figure 1 shows the photograph of the synthesized SnS₂ nanoparticles yield obtained after wash.

Characterization of SnS₂ nanoparticles

The stoichiometric compositions of the as-synthesized SnS₂ nanoparticles were studied with the help of energy dispersive analysis of X-ray (EDAX) employing Philips ESEM having 10–20 keV energy range of the beam. The structural characterization of the particles was done by X-ray diffraction (XRD) using Philips X-ray Diffractometer Xpert MPD employing CuK_α radiation. The as-synthesized SnS₂ nanoparticles were further investigated by transmission electron microscopy (TEM) employing JEOL, JEM 2100. The surface topography study was done by LEO 1430 VP scanning electron microscopy (SEM). An optical absorption study was carried out using a UV–Vis-NRI



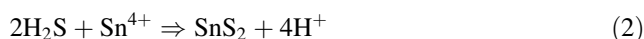
Fig. 1 Photograph of the room temperature synthesized SnS₂ nanoparticles

spectrophotometer (Shimadzu UV-240). The Photoluminescence spectra of SnS₂ nanoparticles were studied using Horiba Yvon FluroMax-4 Spectrofluorometer.

Results and discussion

Synthesis reaction

In the synthesis of SnS₂ nanoparticles by wet chemical technique, stannic chloride pentahydrate (SnCl₄·5H₂O) dissociate to form tin ions and thioacetamide (C₂H₅NS) is the source of sulfur ions. The concentration of tin and sulphide ions is maintained low to avoid immediate precipitation. The SnS₂ nanoparticles are formed by the precipitation reaction between Sn⁺⁴ and H₂S produced by the hydrolysis of thioacetamide. Here, thioacetamide reacts with water at the reaction condition to slowly produce H₂S. The H₂S (bubble) reacts with Sn⁺⁴ to homogeneously form SnS₂ nanoparticles. The formation of SnS₂ nanoparticles may be described by Eqs. (1) and (2) as follows:



Stoichiometric composition studies

The stoichiometric compositions and purity of the synthesized SnS₂ nanoparticles were determined by energy dispersive analysis of X-rays (EDAX) techniques. Figure 2 shows the EDAX spectrum of room temperature synthesized SnS₂ nanoparticles. The obtained weight percentage from EDAX spectrum and the standard weight percentage of tin (Sn) and sulphur (S) elements are tabulated in

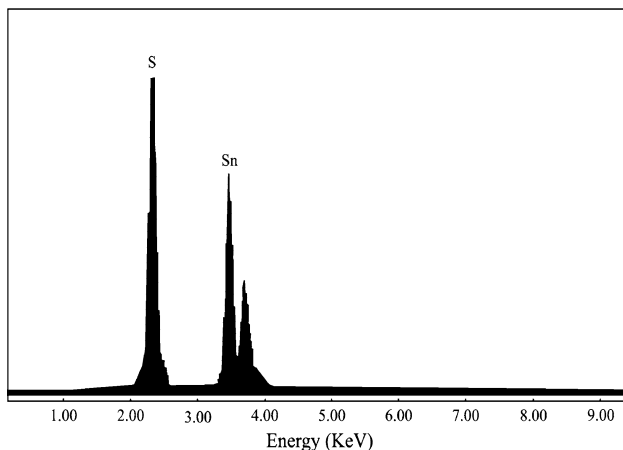


Fig. 2 EDAX spectra of as-synthesized SnS₂ nanoparticles (R.T.)

Table 1 for SnS₂ nanoparticles. The weight percentage data shows that the synthesized SnS₂ nanoparticles are slightly rich in tin content. The EDAX spectrum also showed that the synthesized SnS₂ nanoparticles are free of any other impurities and contaminants. The atomic percentage data of tin and sulphur are also tabulated in Table 1.

Structural studies

The structure, lattice parameters and phase purity of the synthesized SnS₂ nanoparticles were determined by X-ray diffraction (XRD). Figure 3 shows the XRD pattern, all the peaks in the XRD pattern can be readily indexed to the pure hexagonal phase of SnS₂ with lattice constants $a = 3.648 \text{ \AA}$ and $c = 5.899 \text{ \AA}$, which are in good agreement with the standard JCPDS (File No. 23-0677) data.

Average crystallite size was estimated by Scherrer's formula (Panda et al. 2007),

$$L = \frac{K\lambda}{\beta_{2\theta} \cos \theta} \quad (3)$$

where k is the shape factor which typically has value of unity for the spherical shape particle; β is the broadening of diffraction line measured at half maximum intensity

Table 1 Stoichiometric composition of SnS₂ nanoparticles (R.T.) determined by EDAX

Element	Weight percentage (%)		Atomic percentage (%)
	Observed value	Calculated value	
Sn (K)	68.42	64.93	36.96
S (K)	31.58	35.07	63.04

(radians), λ is the wavelength of CuK _{α} radiation and θ is the Bragg's angle. The crystallite sizes of SnS₂ nanoparticles were estimated to be around 3.60 nm from the Scherrer's formula.

The crystallite size and the micro strain in the as-synthesized SnS₂ nanoparticles were estimated by Hall-Williamson relation (Williamson and Hall 1953).

$$\frac{\beta \cos \theta}{\lambda} = \frac{1}{L} + \frac{\varepsilon 4 \sin \theta}{\lambda} \quad (4)$$

The Hall-Williamson equation includes the Scherrer's term of crystallite size (L) and the micro strain term (ε). Here β is full width at half maximum (FWHMs) of the diffraction peaks. The plot of $(\beta \cos \theta)/\lambda$ versus $4(\sin \theta)/\lambda$ for the as-synthesized nanoparticles is shown in the Fig. 4. The reciprocal of an intercept on $(\beta \cos \theta)/\lambda$ axis gives the average crystallite size L . The value of average crystallite size L thus obtained from the plot is $\sim 3.23 \text{ nm}$, which is in good agreement with the crystallite size determined by Scherrer's equation. The slope of the plot gives the amount of residual strain of (-0.0047) . The negative value of residual strain for the SnS₂ nanoparticles indicates it to be compressive strain.

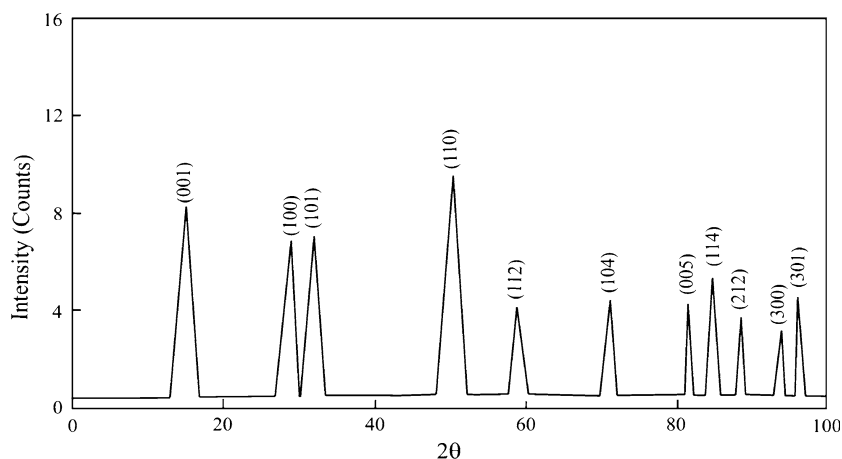
TEM and SAED studies

The morphology and structure of the as-synthesized SnS₂ nanoparticles were studied by transmission electron microscopy (TEM). Figure 5a, b shows a typical high-resolution transmission electron microscopy (HRTEM) image of SnS₂ nanoparticles. The image, Fig. 5a, shows nanoparticles to be spherical in shape, with each nanoparticle displaying lattice fringes, suggesting their crystalline nature. The average particle diameter determined from the TEM image comes out around 3.87 nm. This is in good agreement with the size determined from the XRD. The fringe has lattice spacing of about 0.312 nm, Fig. 5b, which corresponds to $\{100\}$ crystal planes of hexagonal structured SnS₂ (JCPDS No. 23-0677) (Zhu et al. 2006). The corresponding selected area electron diffraction (SAED) pattern in Fig. 6 shows (002), (003) and (111) planes to be prominent, which is consistent with the XRD results presented above.

Surface topography study

The SEM study of the as-synthesized SnS₂ nanoparticles reveals the surface topography. The typical SEM image of the SnS₂ nanoparticles is shown in Fig. 7. The nanoparticles are spherical in shape, corroborating the observations of TEM. They are densely packed possessing compact texture with no pin holes or cracks.

Fig. 3 X-ray diffractogram of SnS₂ nanoparticles (R.T.)



Optical study

The absorption spectrum of SnS₂ nanoparticles was recorded by UV–Vis–NIR spectrophotometer. The SnS₂ nanoparticles were ultrasonically dispersed in acetone. Figure 8 shows the absorption spectrum of SnS₂ nanoparticles

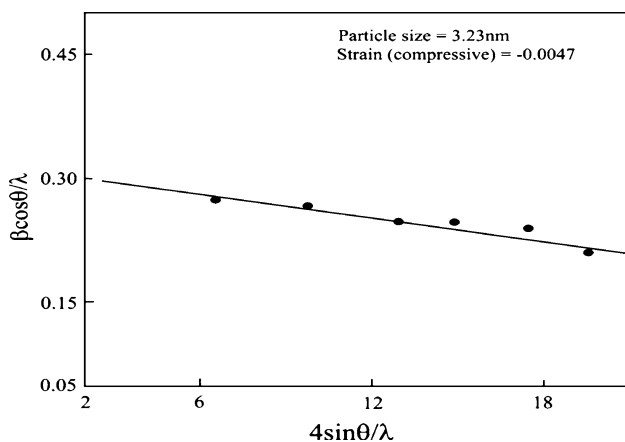
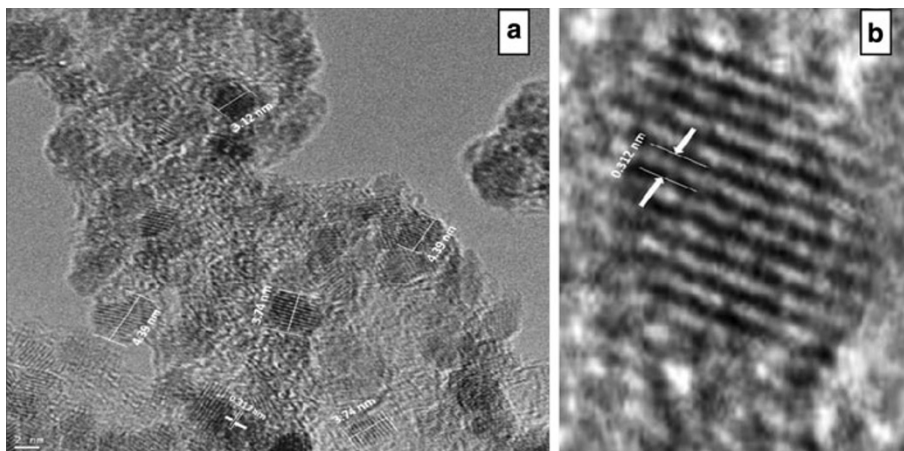


Fig. 4 Hall-Williamson plots for SnS₂ nanoparticles synthesised at room temperature

Fig. 5 HRTEM image of SnS₂ nanoparticles synthesised at room temperature



synthesized at room temperature and it can be seen that the absorption edge lies at 480 nm corresponding to energy value of 2.61 eV. The absorption edge observed at 480 nm clearly indicates a blue shift in comparison to the bulk SnS₂ having absorption edge nearly at 507 nm (Takagahara 1993; Hanumura 1988).

The optical energy bandgap of SnS₂ nanoparticles was determined from the absorption spectrum using the near-band edge absorption relation (Yue et al. 2009).

$$(\alpha h\nu)^n = A(h\nu - E_g)$$

where A is the optical transition dependent constant, E_g is the optical energy bandgap, ν is the frequency of incident beam, h is the Planck's constant and n characterizes the transition. The absorption coefficient (α) was determined by the equation (Ingle and Crouch 1988),

$$\alpha = \frac{A\rho}{Mcl} (\text{cm})^{-1}$$

where A is the absorbance of light through sample, ρ is the density of SnS₂, M is the molecular weight of SnS₂, c is the sample concentration dispersed in acetone and l is the path length of light.

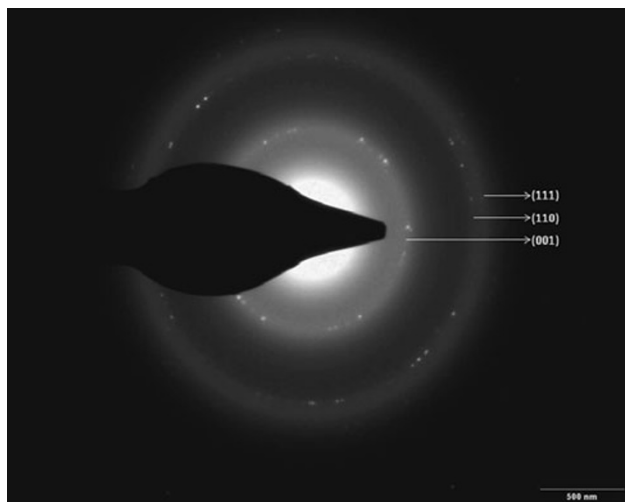


Fig. 6 Selected area electron diffraction pattern of SnS₂ nanoparticles synthesised at room temperature

The analysis of equation showed that, $n = 2$ fitted for the as-synthesized SnS₂ nanoparticles confirming direct allowed transition. The plot of $(\alpha hv)^2$ versus hv for SnS₂ nanoparticles is shown in Fig. 9. The intercept of the straight line on the photon energy axis gives the optical bandgap value E_g of 3.82 eV, which is higher than that of bulk SnS₂ optical bandgap, clearly showing the blue shift arising due to size effect.

Photoluminescence study

The photoluminescence spectra of the as-synthesized SnS₂ nanoparticles were recorded for five excitations viz 250, 300, 350, 400, and 450 nm wavelengths. The spectra obtained for SnS₂ nanoparticles are shown in the Fig. 10.

The spectra exhibit two strong emission peaks at around 550 and 825 nm. The emission at 550 nm (2.25 eV)

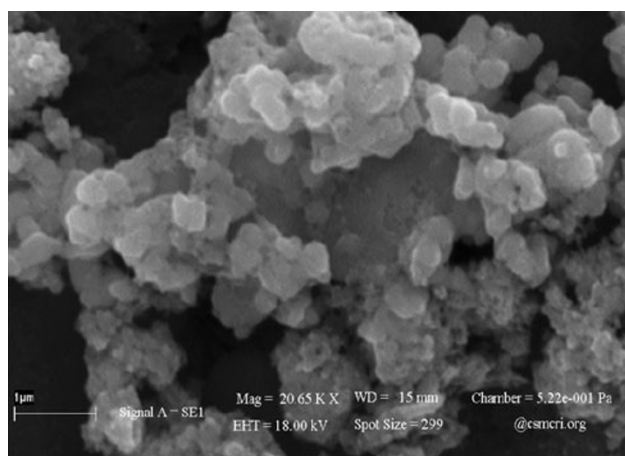


Fig. 7 SEM image of SnS₂ nanoparticles (R.T.)

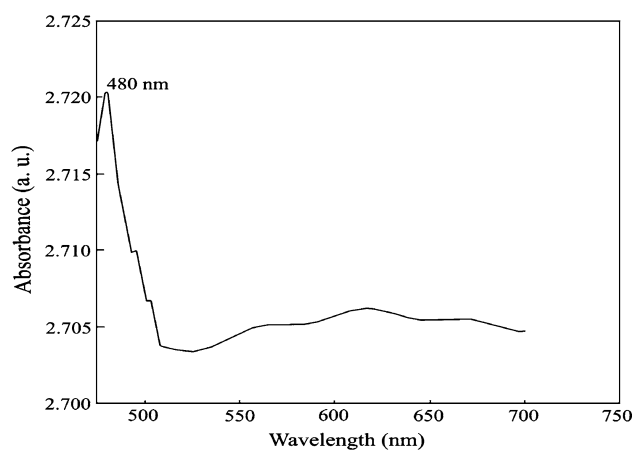


Fig. 8 Absorption spectrum of SnS₂ nanoparticles (R.T.)

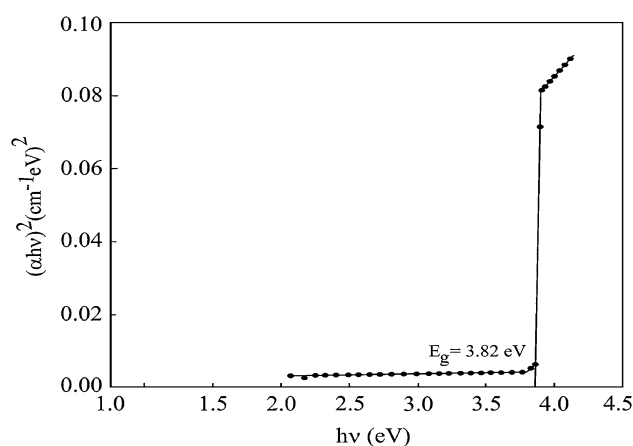


Fig. 9 Plot of $(\alpha hv)^2$ versus hv

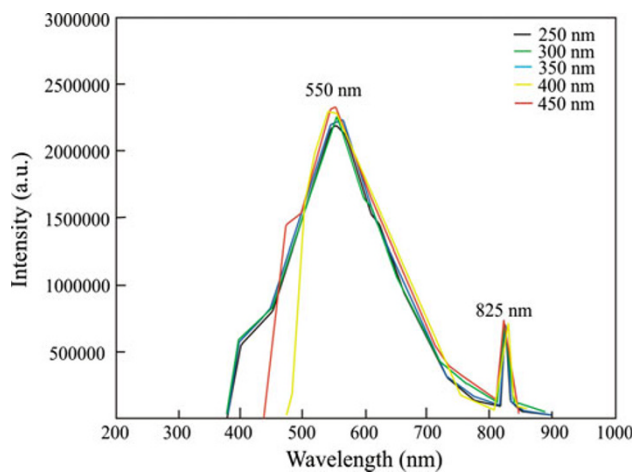


Fig. 10 PL emission spectra of the SnS₂ nanoparticles synthesized at room temperature

corresponds to radiative recombination of quantum confined electron–hole pair whose energy is smaller than the energy bandgap of nanoparticles. The radiative recombination of

excitons is by absorption of electrons lying at higher excited energy levels (Gaponendo 1998). The possible explanation for the origin of the latter peak at 825 nm wavelength might be from the inner deep level emission (Gajendiran and Rajendran 2011). This deep level arises due to the stoichiometric variation in SnS₂ nanoparticles. It was also observed from the PL spectra of the SnS₂ nanoparticles that for five excitation wavelengths, the emissions intensity remains same, meaning the emission intensity is independent of excitation wavelengths.

Conclusions

The SnS₂ nanoparticles have been successfully synthesized by simple wet chemical technique at room temperature. The synthesis was carried out at ambient condition using AR grade non-toxic chemicals without requirement of any sophisticated instruments. The EDAX analysis confirms that the synthesized SnS₂ nanoparticles were perfectly stoichiometric and do not contain any other impurity in them. The X-ray diffraction showed that the synthesized SnS₂ nanoparticles had hexagonal structure. The determined lattice parameters were in good agreement with the reported data. The crystallite size determined from XRD, using Scherrer's equation (3.60 nm) and Hall–Williamson's plot (3.23 nm) were in good agreement with each other. The residual strain determined from Hall–Williamson's plot was (−0.0047), the negative value indicates it to be the compressive strain. The HRTEM image shows nanoparticles to be spherical in shape, with each nanoparticles displaying lattice fringes, suggesting their crystalline nature. The average particle diameter determined from the TEM image is around 3.87 nm, in good agreement with the size determined from the XRD. The HRTEM clearly shows fringes having lattice spacing of about 0.312 nm, which corresponds to {100} planes of hexagonal structured SnS₂. The SEM image show nanoparticles are spherical in shape corroborating TEM observation. They are densely packed possessing compact texture with no pin holes or cracks. The optical bandgap energy 3.82 eV was calculated from the optical absorbance spectrum of the as-synthesized SnS₂ nanoparticles, which is higher than that of bulk SnS₂ optical bandgap, which clearly shows the blue shift arising due to size effect. The photoluminescence spectra of the SnS₂ nanoparticles for five excitation viz 250, 300, 350, 400, and 450 nm wavelengths exhibit two strong emission peaks at around 550 and 825 nm. The PL spectra also showed that for five excitation wavelengths, the emissions intensity remains same which means the emission intensity is independent of excitation wavelengths.

Acknowledgments The authors are thankful to the Sophisticated Instrumentation Centre for Applied Research & Testing (SICART), Vallabh Vidyanagar, Gujarat, India for EDAX, XRD and UV–Vis–NIR spectrophotometer analysis. The authors are grateful to the Central Salt and Marine Chemicals Research Institute (CSMCRI), Bhavnagar, Gujarat, India for HRTEM and SEM analysis. The authors are thankful to the Faculty of Engineering and Technology, M. S. University of Baroda, Vadodara, Gujarat, India for photoluminescence analysis on our samples.

Open Access This article is distributed under the terms of the Creative Commons Attribution License which permits any use, distribution, and reproduction in any medium, provided the original author(s) and the source are credited.

References

- Agrawal A, Patel PD, Lakshminarayana D (1994) Single crystal growth of layered tin monoselenide semiconductor using a direct vapour transport technique. *J. Crystal Growth* 142:344. doi:10.1016/0022-0248(94)90343-3
- Chun D, Walser RM, Bene RW, Courtney TH (1994) Polarity-dependent memory switching in devices with SnSe and SnSe₂ crystals. *Appl Phys Lett* 24:344. doi:10.1063/1.1655019
- Gajendiran J, Rajendran V (2011) Synthesis of SnS₂ nanoparticles by a surfactant-mediated hydrothermal method and their characterization. *Adv Nat Sci Nanosci* 2:015001–015004. doi:10.1088/2043-6262/2/1/015001
- Gaponendo SV (1998) Optical properties of semiconductors nanocrystals. Cambridge University Press, Cambridge. doi:10.2277/0521582415
- Hanumura E (1988) Very large optical nonlinearity of semiconductor microcrystallites. *Phys Rev B* 37:1273–1279. doi:10.1103/PhysRevB.37.1273
- He HY, Huang JF, Cao LY, Wu JP, He Z, Luo L (2007) Photocatalytic activity of mixture of SnS₂ and TiO₂ powders in destruction of methyl orange in water. *J Optoelectron Adv Mater* 9:3781–3784
- Ingle JDJ, Crouch SR (1988) Spectrochemical analysis. Prentice Hall, Englewood Cliffs, pp 372–381
- Li Y, Xie H, Tu J (2009) Nanostructured SnS/carbon composite for supercapacitor. *Mater Lett* 63:1785–1787. doi:10.1016/j.matlet.2009.05.036
- Loferski JJ (1956) Theoretical considerations governing the choice of the optimum semiconductor for photovoltaic solar energy conversion. *J Appl Phys* 27:777. doi:10.1063/1.1722483
- Lokhande CD (1990) A chemical method for tin disulphide thin film deposition. *J Phys D Appl Phys* 23:1703. doi:10.1088/0022-3727/23/12/032
- Panda SK, Antonakos A, Liarokapis E, Bhattacharya S, Chaudhuri S (2007) Optical properties of nanocrystalline SnS₂ thin films. *Mater Res Bull* 42:576–583. doi:10.1016/j.materresbull.2006.06.028
- Patil SG, Fredgold RH (1971) Electrical and photoconductive properties of SnS₂ crystals. *J Pure Appl Phys* 4:718. doi:10.1088/0022-3727/4/5/312
- Rao MM, Jayalakshmi M, Reddy RS (2004) Time-selective hydrothermal synthesis of SnS nanorods and nanoparticles by thiourea hydrolysis. *Chem Lett* 33:1044. doi:10.1246/cl.2004.1044
- Ross CA, Hwang M, Shima H, Smith HI, Farhoud M, Savas TA (2002) Magnetic properties of arrays of electrodeposited nanowires. *J Magn Magn Mater* 249:200–207. doi:10.1016/S0304-8853(02)00531-0

- Takagahara T (1993) Effects of dielectric confinement and electron-hole exchange interaction on excitonic states in semiconductor quantum dots. *Phys Rev B* 47:4569–4584. doi:[10.1103/PhysRevB.47.4569](https://doi.org/10.1103/PhysRevB.47.4569)
- Williamson GK, Hall WH (1953) X-ray line broadening from filed aluminium and wolfram. *Acta Metall* 1:22–31. doi:[10.1016/0001-6160\(53\)90006-6](https://doi.org/10.1016/0001-6160(53)90006-6)
- Yang C, Wang W, Shan Z, Huang F (2009) Preparation and photocatalytic activity of high-efficiency visible-light-responsive photocatalyst SnS_x/TiO₂. *J Solid State Chem* 182:807–812. doi:[10.1016/j.jssc.2008.12.018](https://doi.org/10.1016/j.jssc.2008.12.018)
- Yi G, Schwarzacher W (1999) Single crystal superconductor nanowires by electrodeposition. *Appl Phys Lett* 74:1746. doi:[10.1063/1.123675](https://doi.org/10.1063/1.123675)
- Yue GH, Peng DL, Yan PX, Wang LS, Wang W, Luo XH (2009) Structure and optical properties of SnS thin film prepared by pulse electrodeposition. *J Alloy Compd* 468:254–257. doi:[10.1016/j.jallcom.2008.01.047](https://doi.org/10.1016/j.jallcom.2008.01.047)
- Zach MP, Ng KH, Penner RM (2000) Molybdenum nanowires by electrodeposition. *Science* 290:2120. doi:[10.1126/science.290.5499.2120](https://doi.org/10.1126/science.290.5499.2120)
- Zhang YC, Du ZN, Li SY, Zhang M (2010) Novel synthesis and high visible light photocatalytic activity of SnS₂ nanoflakes from SnCl₂·2H₂O and S powders. *Appl Catal B* 95:153–159. doi:[10.1016/j.apcatb.2009.12.022](https://doi.org/10.1016/j.apcatb.2009.12.022)
- Zhang YC, Du ZN, Li KW, Zhang M, Dionysiou DD (2011) High-performance visible-light-driven SnS₂/SnO₂ nanocomposite photocatalyst prepared via in situ hydrothermal oxidation of SnS₂ nanoparticles. *Appl Mater Interface* 3:1528–1537. doi:[10.1021/am200102y](https://doi.org/10.1021/am200102y)
- Zhu H, Ji X, Yang D (2006) Hydrothermal synthesis and characterization of novel aloe-like SnS₂ nanostructures. *J Mater Sci* 41:3489–3492. doi:[10.1007/s10853-005-5911-y](https://doi.org/10.1007/s10853-005-5911-y)